

isc Silicon PNP Darlington Power Transistor

MJE703

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
- : $V_{(BR)CEO} = -80 \text{ V}$
- DC Current Gain-
- : h_{FE} = 750(Min) @ I_C= -2 A = 100(Min) @ I_C= -4A
- Complement to Type MJE803
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

· Designed for general-purpose amplifier and low-speed switching applications

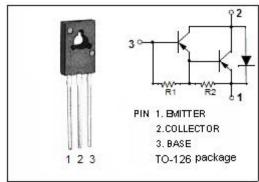


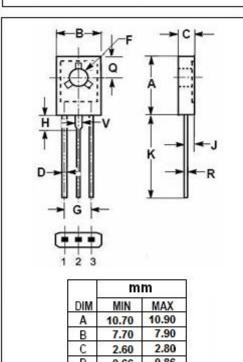
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-80	V
V _{CEO}	Collector-Emitter Voltage	-80	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-4	Α
I _B	Base Current	-0.1	Α
Pc	Collector Power Dissipation T_c =25 $^{\circ}$ C	40	W
Ti	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.13	°C/W





	mm	
DIM	MIN	MAX
Α	10.70	10.90
В	7.70	7.90
C	2.60	2.80
D	0.66	0.86
F	3.10	3.30
G	4.48	4.68
Н	2.00	2.20
J	1.35	1.55
K	16.10	16.30
Q	3.70	3.90
R	0.40	0.60
V	1.17	1.37



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -50mA; I _B = 0	-80		V
V _{CE} (sat)-1	Collector-Emitter Saturation Voltage	I _C = -2A; I _B = -40mA		-2.8	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = -4A; I _B = -40mA		-3.0	V
V _{BE(on)-1}	Base-Emitter On Voltage	I _C = -2A; V _{CE} = -3V		-2.5	V
V _{BE(on)-2}	Base-Emitter On Voltage	Ic= -4A; Vc== -3V		-3.0	V
I _{CEO}	Collector Cutoff Current	V _{CE} = -80V; I _B = 0		-0.1	mA
I _{CBO}	Collector Cutoff Current	V _{CB} = -80V; I _E = 0 V _{CB} = -80V; I _E = 0;T _C = 100°C		-0.1 -0.5	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0		-2.0	mA
h _{FE-1}	DC Current Gain	I _C = -2 A ; V _{CE} = -3V	750		
h _{FE-2}	DC Current Gain	Ic= -4A ; Vc= -3V	100		

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